

**FEATURES:**

- N channel FET switches with no parasitic diode to Vcc
  - Isolation under power-off conditions
  - No DC path to Vcc or GND
  - 5V tolerant in OFF and ON state
- 5V tolerant I/Os
- Low Ron, 4Ω typical
- Flat Ron characteristics over operating range
- Rail-to-rail switching 0 - 5V
- Bidirectional dataflow with near-zero delay: no added ground bounce
- Excellent Ron matching between channels
- Vcc operation: 2.3V to 3.6V
- High bandwidth - up to 500MHz
- LVTTL-compatible control Inputs
- Undershoot Clamp Diodes on all switch and control Inputs
- Low I/O capacitance, 4pF typical
- Available in 80-pin QVSOP package

**APPLICATIONS:**

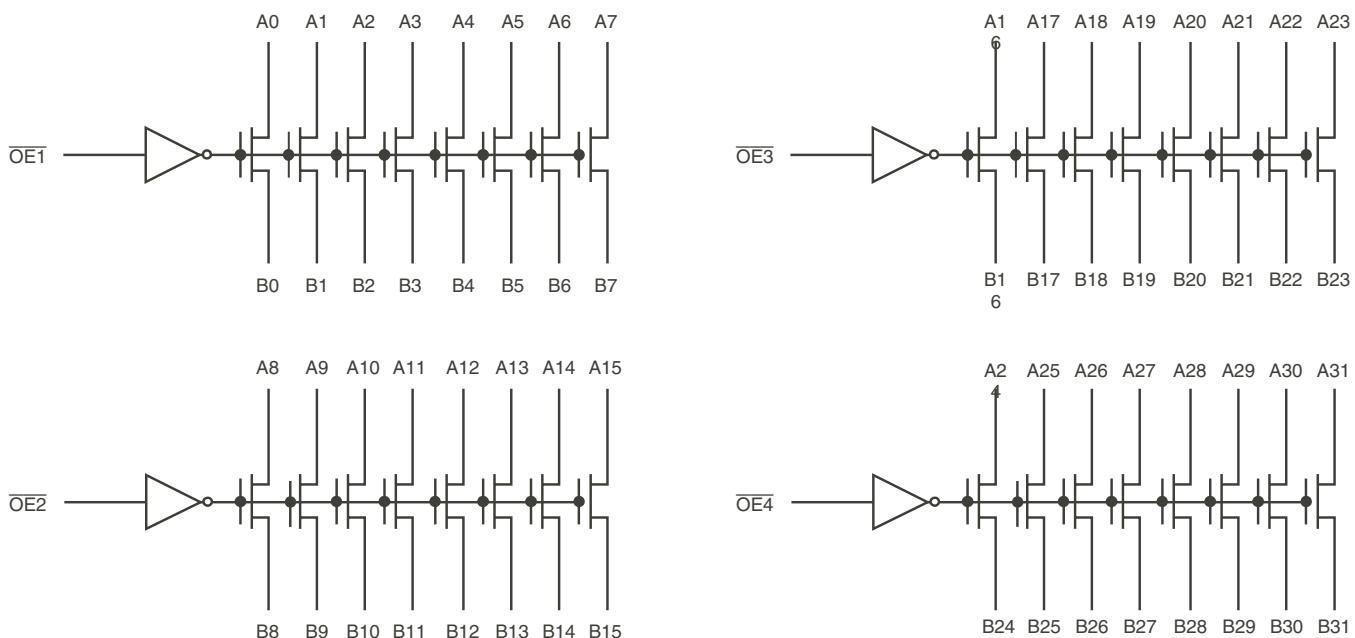
- Hot-swapping
- 10/100 Base-T, Ethernet LAN switch
- Low distortion analog switch
- Replaces mechanical relay
- ATM 25/155 switching

**DESCRIPTION:**

The QS34XVH245 HotSwitch is a high bandwidth 32-bit bus switch. The QS34XVH245 has very low ON resistance, resulting in under 250ps propagation delay through the switch. The switches can be turned ON under the control of individual LVTTL-compatible Output Enable (OE) signals for bidirectional data flow with no added delay or ground bounce. In the ON state, the switches can pass up to 5V. In the OFF state, the switches offer very high impedance at the terminals.

The combination of near-zero propagation delay, high OFF impedance, and over-voltage tolerance makes the QS34XVH245 ideal for high performance communications applications.

The QS34XVH245 is characterized for operation from -40°C to +85°C.

**FUNCTIONAL BLOCK DIAGRAM**

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**INDUSTRIAL TEMPERATURE RANGE**

**JANUARY 2013**

## PIN CONFIGURATION

NC	1	80	Vcc
A0	2	79	$\overline{OE}_1$
A1	3	78	B0
A2	4	77	B1
A3	5	76	B2
A4	6	75	B3
A5	7	74	B4
A6	8	73	B5
A7	9	72	B6
GND	10	71	B7
NC	11	70	Vcc
A8	12	69	$\overline{OE}_2$
A9	13	68	B8
A10	14	67	B9
A11	15	66	B10
A12	16	65	B11
A13	17	64	B12
A14	18	63	B13
A15	19	62	B14
GND	20	61	B15
NC	21	60	Vcc
A16	22	59	$\overline{OE}_3$
A17	23	58	B16
A18	24	57	B17
A19	25	56	B18
A20	26	55	B19
A21	27	54	B20
A22	28	53	B21
A23	29	52	B22
GND	30	51	B23
NC	31	50	Vcc
A24	32	49	$\overline{OE}_4$
A25	33	48	B24
A26	34	47	B25
A27	35	46	B26
A28	36	45	B27
A29	37	44	B28
A30	38	43	B29
A31	39	42	B30
GND	40	41	B31

QVSOP  
TOP VIEW

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Supply Voltage to Ground	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	DC Switch Voltage Vs	-0.5 to +5.5	V
VTERM <sup>(3)</sup>	DC Input Voltage V <sub>IN</sub>	-0.5 to +5.5	V
VAC	AC Input Voltage (pulse width $\leq$ 20ns)	-3	V
I <sub>OUT</sub>	DC Output Current (max. sink current/pin)	120	mA
T <sub>TG</sub>	Storage Temperature	-65 to +150	°C

### NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Vcc terminals.
3. All terminals except Vcc .

## CAPACITANCE (TA = +25°C, F = 1MHz, V<sub>IN</sub> = 0V, V<sub>OUT</sub> =

Symbol	Parameter <sup>(1)</sup>	Typ.	Max.	Unit
C <sub>IN</sub>	Control Inputs	3	5	pF
C <sub>I/O</sub>	Quickswitch Channels (Switch OFF)	4	6	pF
C <sub>I/O</sub>	Quickswitch Channels (Switch ON)	8	12	pF

### NOTE:

1. This parameter is guaranteed but not production tested.

## PIN DESCRIPTION

Pin Names	I/O	Description
$\overline{OE}_X$	I	Output Enable
A <sub>X</sub>	I/O	Bus A
B <sub>X</sub>	I/O	Bus B

## FUNCTION TABLE<sup>(1)</sup>

$\overline{OE}_X$	Function
H	Disconnected
L	Connect (A <sub>X</sub> = B <sub>X</sub> )

### NOTE:

1. H = HIGH Voltage Level  
L = LOW Voltage Level

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

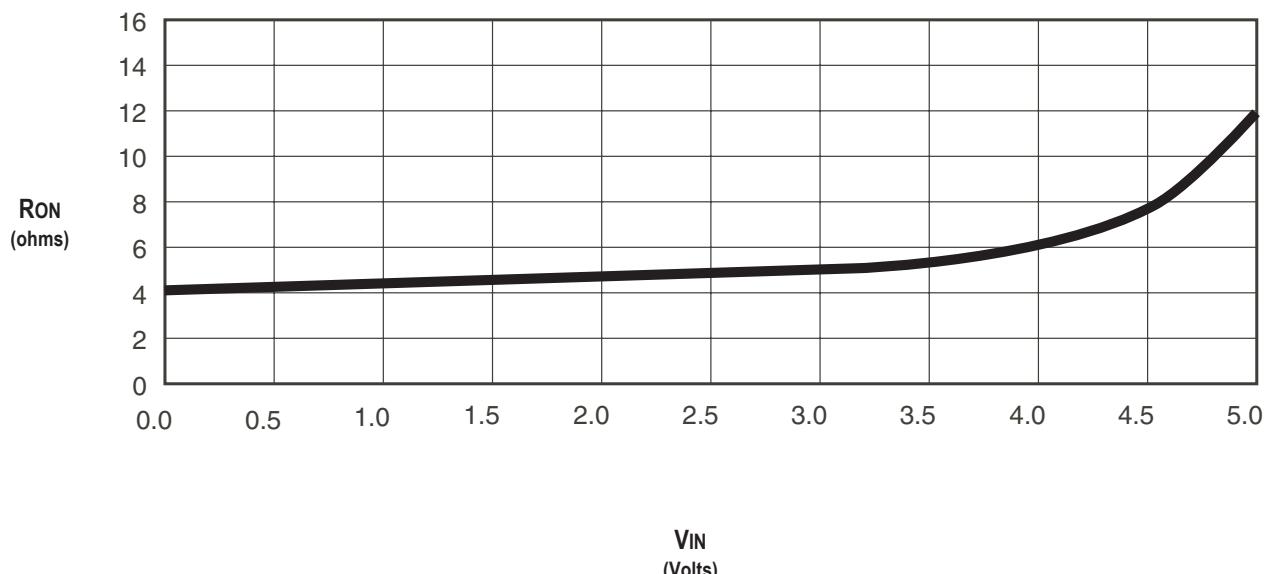
Industrial: TA =  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ , Vcc = 3.3V  $\pm 0.3\text{V}$

Symbol	Parameter	Test Conditions			Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	Vcc = 2.3V to 2.7V		1.7	—	—	V
			Vcc = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Inputs	Vcc = 2.3V to 2.7V		—	—	0.7	V
			Vcc = 2.7V to 3.6V		—	—	0.8	
IIN	Input Leakage Current (Control Inputs)	0V $\leq$ VIN $\leq$ Vcc			—	—	$\pm 1$	$\mu\text{A}$
IOZ	Off-State Current (Hi-Z)	0V $\leq$ VOUT $\leq$ 5V, Switches OFF			—	—	$\pm 1$	$\mu\text{A}$
IOFF	Data Input/Output Power Off Leakage	VIN or VOUT 0V to 5V, Vcc = 0V			—	—	$\pm 1$	$\mu\text{A}$
RON	Switch ON Resistance	Vcc = 2.3V Typical at Vcc = 2.5V	VIN = 0V	ION = 30mA	—	6	8	$\Omega$
			VIN = 1.7V	ION = 15mA	—	7	9	
		Vcc = 3V	VIN = 0V	ION = 30mA	—	4	6	
			VIN = 2.4V	ION = 15mA	—	5	8	

NOTE:

1. Typical values are at Vcc = 3.3V and TA = 25°C.

## TYPICAL ON RESISTANCE vs VIN AT Vcc = 3.3V



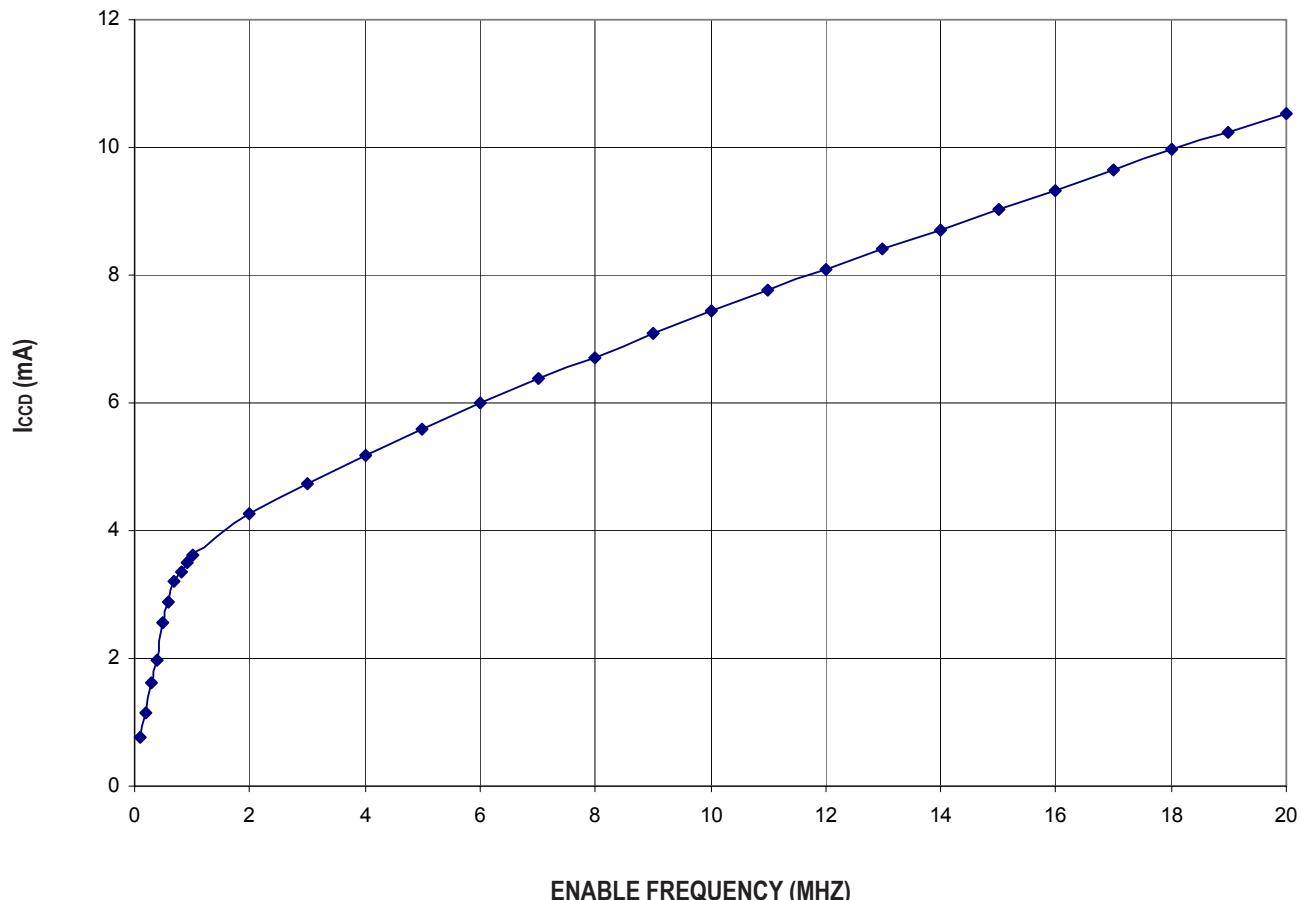
## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>	Min.	Typ.	Max.	Unit
I <sub>CCQ</sub>	Quiescent Power Supply Current	V <sub>CC</sub> = Max., V <sub>IN</sub> = GND or V <sub>CC</sub> , f = 0	—	8	16	mA
ΔI <sub>CC</sub>	Power Supply Current <sup>(2,3)</sup> per Input HIGH	V <sub>CC</sub> = Max., V <sub>IN</sub> = 3V, f = 0 per Control Input	—	—	30	μA
I <sub>CCD</sub>	Dynamic Power Supply Current per Output Enable Control Input <sup>(4)</sup>	V <sub>CC</sub> = 3.3V, A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	See Typical I <sub>CCD</sub> vs Enable Frequency graph below			

### NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
2. Per input driven at the specified level. A and B pins do not contribute to ΔI<sub>CC</sub>.
3. This parameter is guaranteed but not tested.
4. This parameter represents the current required to switch internal capacitance at the specified frequency. The A and B inputs do not contribute to the Dynamic Power Supply Current. This parameter is guaranteed but not production tested.

## TYPICAL I<sub>CCD</sub> VS ENABLE FREQUENCY CURVE AT V<sub>CC</sub> = 3.3V



## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

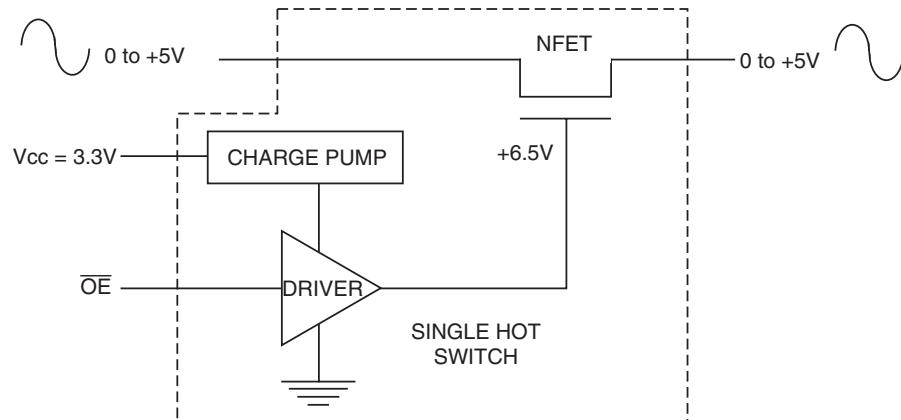
TA = -40°C to +85°C

Symbol	Parameter	Vcc = 2.5 ± 0.2V <sup>(1)</sup>		Vcc = 3.3 ± 0.3V <sup>(1)</sup>		Unit
		Min. <sup>(4)</sup>	Max.	Min. <sup>(4)</sup>	Max.	
tPLH tPHL	Data Propagation Delay <sup>(2,3)</sup> Ax to/from Bx	—	0.2	—	0.2	ns
tPZH tPZL	Switch Turn-On Delay OEx to Ax/Bx	1.5	8	1.5	7	ns
tPHZ tPLZ	Switch Turn-Off Delay OEx to Ax/Bx	1.5	7	1.5	6.5	ns
fOEx	Operating Frequency - Enable <sup>(2,5)</sup>	—	10	—	20	MHz

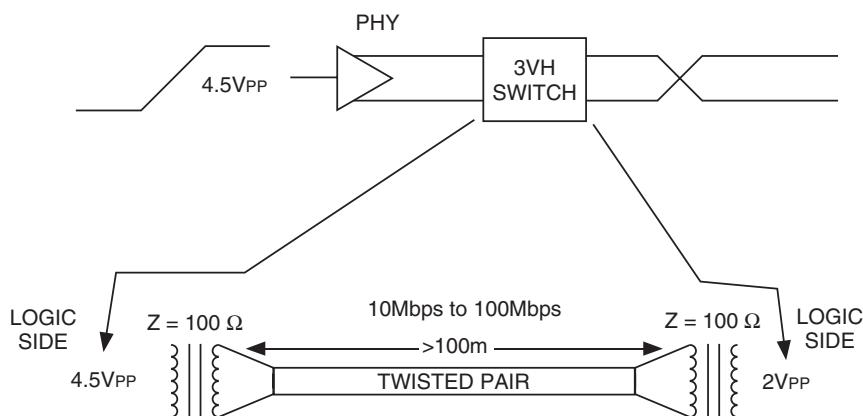
### NOTES:

1. See Test Conditions under TEST CIRCUITS AND WAVEFORMS.
2. This parameter is guaranteed but not production tested.
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.2ns at CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.
4. Minimums are guaranteed but not production tested.
5. Maximum toggle frequency for OEx control input (pass voltage > Vcc, VIN = 5V, RLOAD ≥ 1MΩ, no CLOAD).

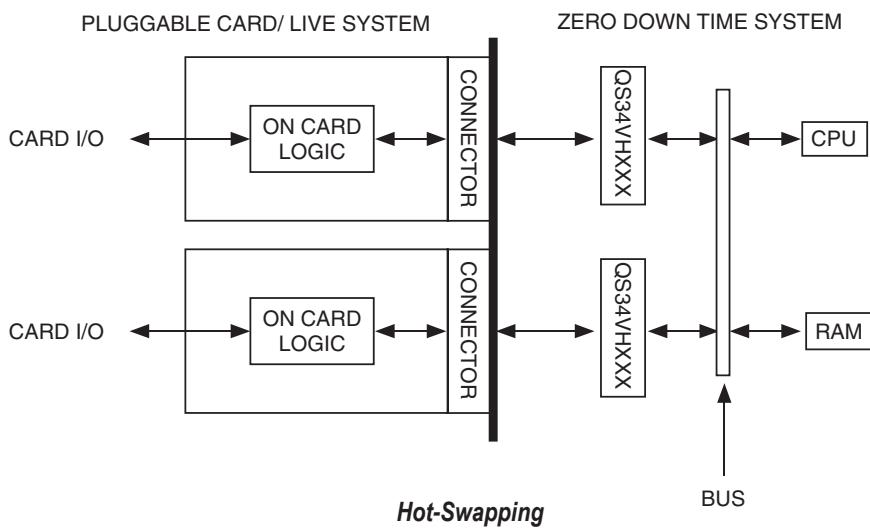
## SOME APPLICATIONS FOR HOTSWITCH PRODUCTS



*Rail-to-Rail Switching*



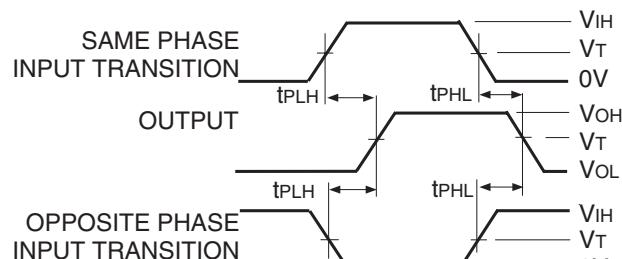
*Fast Ethernet Data Switching (LAN Switch)*



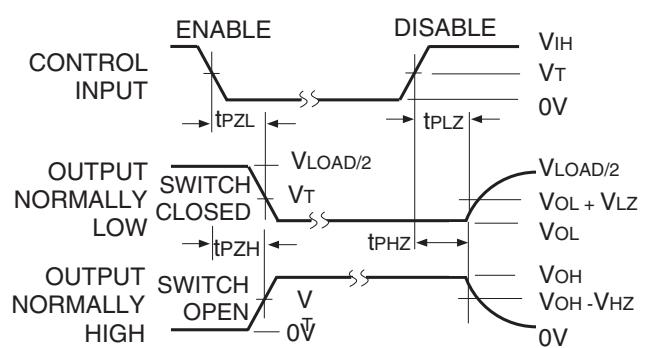
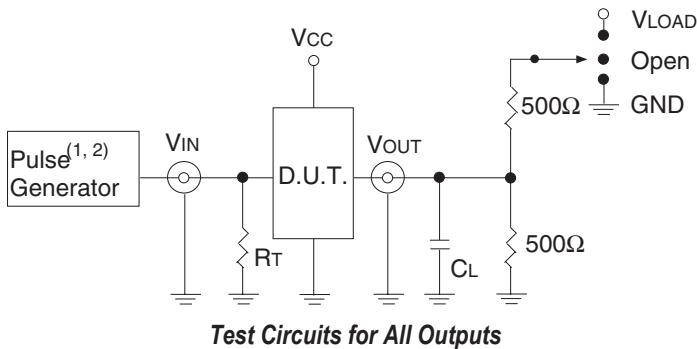
## TEST CIRCUITS AND WAVEFORMS

### TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
$V_{LOAD}$	6	$2 \times V_{CC}$	V
$V_{IH}$	3	$V_{CC}$	V
$V_T$	1.5	$V_{CC}/2$	V
$V_{LZ}$	300	150	mV
$V_{HZ}$	300	150	mV
$C_L$	50	30	pF



Propagation Delay



#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

#### Enable and Disable Times

#### DEFINITIONS:

$C_L$  = Load capacitance: includes jig and probe capacitance.

$R_T$  = Termination resistance: should be equal to  $Z_{OUT}$  of the Pulse Generator.

#### NOTES:

1. Pulse Generator for All Pulses: Rate  $\leq 10MHz$ ;  $t_f \leq 2.5ns$ ;  $t_r \leq 2.5ns$ .
2. Pulse Generator for All Pulses: Rate  $\leq 10MHz$ ;  $t_f \leq 2ns$ ;  $t_r \leq 2ns$ .

## SWITCH POSITION

Test	Switch
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND
$t_{PD}$	Open

## ORDERING INFORMATION

QS	<u>XXXXX</u>	<u>XX</u>	<u>X</u>		
Device Type	Package				
				Blank	Tube or Tray Tape and Reel
				8	
			Q3G		80-Pin QVSOP - Green
				34XVH245	2.5V / 3.3V 32-Bit High Bandwidth Bus Switch

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